## EE 331 Spring 2014 Homework #2 Solutions

Problem 1



Problem 2

3.1

$$\begin{split} & \phi_{j} = V_{T} \ln \frac{N_{A}N_{D}}{n_{i}^{2}} = (0.025V) \ln \frac{(10^{19} \cdot cm^{-3})(10^{18} \cdot cm^{-3})}{10^{20} \cdot cm^{-6}} = 0.979V \\ & w_{do} = \sqrt{\frac{2\varepsilon_{s}}{q} \left(\frac{1}{N_{A}} + \frac{1}{N_{D}}\right)} \phi_{j} = \sqrt{\frac{2(11.7 \cdot 8.854 \times 10^{-14} F \cdot cm^{-1})}{1.602 \times 10^{-19} C} \left(\frac{1}{10^{19} cm^{-3}} + \frac{1}{10^{18} cm^{-3}}\right) (0.979V)} \\ & w_{do} = 3.73 \times 10^{-6} cm = 0.0373 \mu m \\ & x_{n} = \frac{w_{do}}{1 + \frac{N_{D}}{N_{A}}} = \frac{0.0373 \mu m}{1 + \frac{10^{18} cm^{-3}}{10^{19} cm^{-3}}} = 0.0339 \ \mu m \mid x_{p} = \frac{w_{do}}{1 + \frac{N_{A}}{N_{D}}} = \frac{0.0373 \mu m}{1 + \frac{10^{19} cm^{-3}}{10^{18} cm^{-3}}} = 3.39 \times 10^{-3} \ \mu m \\ & E_{MAX} = \frac{qN_{A}x_{p}}{\varepsilon_{s}} = \frac{\left(1.60 \times 10^{-19} C\right)(10^{19} cm^{-3})(3.39 \times 10^{-7} cm)}{11.7 \cdot 8.854 \times 10^{-14} F / cm} = 5.24 \times 10^{5} \frac{V}{cm} \end{split}$$

### Problem 3

3.17  

$$T = \frac{qV_T}{k} = \frac{1.60 \times 10^{-19} C(0.025V)}{1.38 \times 10^{-23} J/K} = 290 K$$

#### Problem 4

4.

Total current in a device is the sum of drift and diffusion currents for the two types of carriers: electrons and holes.

Drift current happens whenever there is an electric field (built-in or external).

The direction of the drift current depends on the direction of electric field.

Diffusion current is due to the random thermal motion of carriers. Diffusion happens when there is a gradient (change with respect to location) of the carrier concentrations.

The electron diffusion current is the direction of the gradient (derivative in 1D), but the hole diffusion current is in opposite direction to the gradient (positive carriers down the slope).

Under equilibrium conditions, drift current and diffusion currents are equal and opposite (for each carrier), so the total current is zero.

#### Problem 5

Oops, didn't actually assign a Problem 5, so everyone gets an A+ on this question.

# Problem 6

6. A. E: Method Electric field  
B. 
$$\Psi$$
: Built-in Voltage  
C.  $\rho$ : Charge density  
ID Poisson's equation  
(from lecture 6 slide # 3):  

$$\frac{d^2 \Psi}{dx^2} = -\frac{dE}{dx} = -\frac{\rho}{E}$$
Notice how you integrate  
the curves as you go from  
 $\rho \rightarrow E \rightarrow \Psi$   
which is just another  
way to look at ID Poisson equation.

# Problem 7

3.28  

$$V_{D} = nV_{T} \ln\left(1 + \frac{I_{D}}{I_{S}}\right) | 10^{-14} \le I_{S} \le 10^{-12} | V_{D} = (0.025V) \ln\left(1 + \frac{10^{-3}A}{10^{-12}A}\right) = 0.518 V$$

$$V_{D} = (0.025V) \ln\left(1 + \frac{10^{-3}A}{10^{-14}A}\right) = 0.633 V | So, 0.518 V \le V_{D} \le 0.633 V$$

# Problem 8

5. J&B P3.33

(a) At  $30^{\circ}C_{\bullet}V_T = 26 \ mV$ 

$$v_D = V_T ln \left(\frac{l_D}{l_S} + 1\right) = 0.754 V$$

(b) Now the temperature is 50°C,  $\Delta T = 20 K$ , then

$$\Delta v_D = \Delta T \frac{dv_D}{dT} = -36 mV$$
$$v_D (50^{\circ}\text{C}) = v_D (30^{\circ}\text{C}) + \Delta v_D = 0.718 V$$

### Problem 9

6. J&B P3.40

The potential drop across the diode is just the area of the triangle in E(x) plot, we have

$$\phi_j + v_R = \frac{1}{2} w_d E_{MAX}$$

$$E_{MAX} = \frac{2(\phi_j + v_R)}{w_d}$$

$$\frac{w_d}{w_{d0}} = \sqrt{1 + \frac{v_R}{\phi_j}}$$

$$E_{MAX} = \frac{2(\phi_j + v_R)}{w_{d0}\sqrt{1 + \frac{v_R}{\phi_j}}} = \frac{2\sqrt{(\phi_j + v_R)\phi_j}}{w_{d0}}$$

Then

$$v_{R} = \frac{\left(\frac{W_{d0}E_{MAX}}{2}\right)^{2}}{\phi_{j}} - \phi_{j} = 374.4 V$$

### Problem 10

 J&B P3.72 (a,b). Work all 4 diode circuits (a – d). State whether each diode is ON or OFF.

(a) ideal diode model



(b) constant voltage drop diode model with Von = 0.7 V

